

Local defects and ferromagnetism in graphene layers.

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We study the changes in the electronic structure induced by lattice defects in graphene planes. In many cases, lattice distortions give rise to localized states at the Fermi level. Electron-electron interactions lead to the existence of local moments. The RKKY interaction between these moments is always ferromagnetic, due to the semimetallic properties of graphene.

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Introduction. A number of recent experiments suggest that pure graphite behaves as a highly correlated electron system[1]. In particular it shows a metal-insulator transition in magnetic fields and insulating behavior in the direction perpendicular to the planes in different samples[1, 2, 3, 4, 5, 6, 7, 8]. Recent results show ferromagnetic behavior[9], enhanced by proton bombardment[10], what opens up a new way to the creation of organic magnets[11]. In this paper we study the formation of local moments near simple defects. It is shown that many tyoes of lattice distortions, like cracks and vacancies, can induce localized states at the Fermi level, leading to the existence of local moments. The RKKY interaction between these moments is always ferromagnetic due to the semimetallic properties of graphite. Hence, the RKKY interaction does not lead to frustration and spin glass features.

The model. The conduction band of graphite is well described by a tight binding model which includes the π orbitals which are perpendicular to the graphite planes at each C atom[12]. If the interplane hopping is neglected, this model describes a semimetal, with zero density of states at the Fermi energy, and where the Fermi surface is reduced to two inequivalent K-points located at the corner of the hexagonal Brillouin Zone. The low-energy excitations with momenta in the vicinity of the Fermi points have a linear dispersion and can be described by a continuum model which reduces to the Dirac equation in two dimensions[12, 13, 14, 15, 16]. The Hamiltonian density of the system is

$$\mathcal{H}_0 = \hbar v_F \int d^2\mathbf{r} \bar{\Psi}(\mathbf{r}) (i\sigma_x \partial_x + i\sigma_y \partial_y) \Psi(\mathbf{r}), \quad (1)$$

where the components of the two-dimensional spinor $\Psi(\mathbf{r}) = (\Psi_1(\mathbf{r}), \Psi_2(\mathbf{r}))$ correspond to the Bloch states of the two sublattices in the honeycomb structure, independent in the absence of interactions. In the clean two-dimensional system there is no room for low energy electronic instabilities, the short range interactions being irrelevant due to the vanishing density of states at the Fermi level.

It is known that disorder significantly changes the states described by the two dimensional Dirac equation[17, 18, 19], and, usually, the density of states

at low energies is increased. Lattice defects, such as pentagons and heptagons, or dislocations, can be included in the continuum model by means of a non-abelian gauge field[14, 20] that reproduces the effects of the curvature of the lattice and the possible exchange of Fermi points. Within the same theoretical scheme it has also been shown that certain types of disorder randomly distributed in the graphene lattice enhances the effect of the interactions[21] and can stabilize new phases. In addition, a graphene plane can show states localized at interfaces[22, 23], which, in the absence of other types of disorder lie at the Fermi energy. Structures with mixed sp^2 and sp^3 bonding can also lead to localized states[24].

The tight binding model defined by the π orbitals at the lattice sites can have edge states when the sites at the edge belong all to the same sublattice[22, 23, 25](zigzag edge). These states lie at zero energy which for neutral graphene planes correspond to the Fermi energy. In the continuum model described earlier localized states are normalizable solutions $(\Psi_1(\mathbf{r}), \Psi_2(\mathbf{r}))$ of the Dirac equation:

$$\begin{aligned} (\partial_x + i\partial_y) \Psi_1(\mathbf{r}) &= 0 \\ (\partial_x - i\partial_y) \Psi_2(\mathbf{r}) &= 0 \end{aligned} \quad (2)$$

These equations are satisfied if $\Psi_1(\mathbf{r})$ is an analytic function of $z = x + iy$ and $\Psi_2(\mathbf{r}) = 0$, or if $\Psi_1(\mathbf{r}) = 0$ and $\Psi_2(\mathbf{r})$ is an analytic function of $\bar{z} = x - iy$. Zigzag edge states can be obtained as follows. Consider a semi-infinite honeycomb lattice with an edge at $y = 0$ and which occupies the half plane $x > 0$. A possible solution which decays as $x \rightarrow \infty$ is

$$\Psi_1(x, y) \propto e^{-kz} = e^{iky} e^{-kx}, \Psi_2(\mathbf{r}) = 0.$$

These solutions satisfy the boundary conditions at $y = 0$ if the last column of carbon atoms belong to the sublattice where the component Ψ_1 is defined. Then, the next column belongs to the other sublattice, where the amplitude of the state is, by construction, zero.

This kind of solutions can be generalized to describe other types of extended defects that will be produced in experiments where graphite samples are bombarded by protons. In a strongly disordered sample, large defects

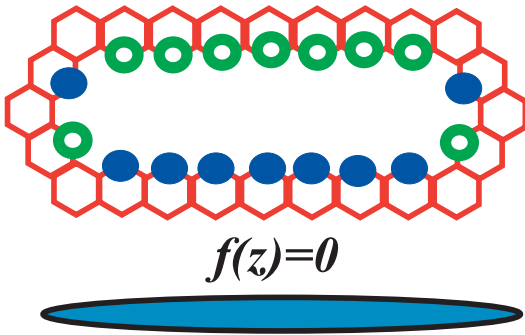


FIG. 1: Elongated crack in the honeycomb structure. The crack is such that the sites in the upper edge belong to one sublattice, while those at the lower edge belong to the other. Bottom: approximate cut in the complex plane which can be used to represent this crack at long distances.

made up of many vacancies can exist. These defects will give rise to localized states, when the termination at the edges is locally similar to the surfaces discussed above. Note that, if the bonds at the edges are saturated by bonding to other elements, like hydrogen, the states at these sites are removed from the Fermi energy, but a similar boundary problem arises for the remaining π orbitals. The only possible localized states can exist at zero energy, where the density of extended states vanishes. The wave functions obtained from the Dirac equations will be normalizable and analytic functions of the variables $z = x + iy$ or $\bar{z} = x - iy$ of the form

$$\Psi(z) \equiv [f(z), 0]$$

obeying the boundary conditions imposed by the shape of the defect.

Extended vacancies with approximate circular shape can support solutions of the type

$$f(z) \propto z^{-n}, n > 1.$$

By using conformal mapping techniques, solutions can be found with the boundary conditions appropriate to the shapes of different defects.

A simple case is the elongated crack depicted in Fig.[1], which we assume to extend from $x = -a$ to $x = a$, and to have a width comparable to the lattice constant along the y axis. The analytic function $f(z)$ associated with localized states near a crack of this shape should satisfy $\text{Re} f(z) = 0$ at the crack edges, because the boundaries of the crack include atoms from the two sublattices. Hence, the boundary of the crack leads to a branch cut in the complex function $f(z)$. Labelling edge states by a quantum number n , we find that the function Ψ can be written for these states as:

$$\Psi_n \equiv \left\{ \text{Re} \left[\frac{A}{z^n \sqrt{z^2 - a^2}} \right], 0 \right\}.$$

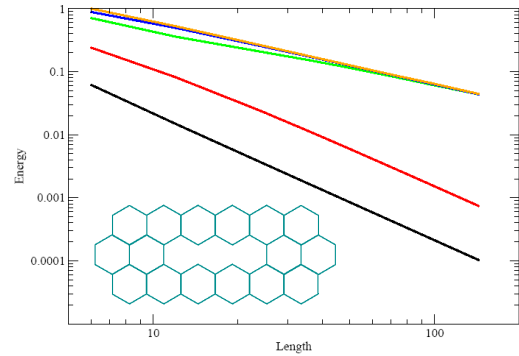


FIG. 2: Energy of the five states with positive energy closest to $\epsilon = 0$ for a cluster of size $L \times L$ which contains at the center the defect shown in the inset. Periodic boundary conditions are used. The spectrum is symmetric around $\epsilon = 0$.

A similar solution is obtained by exchanging the upper by the lower spinor component, and replacing $z \leftrightarrow \bar{z}$. Because of the discreteness of the lattice, the allowed values of n should be smaller than the number of lattice units spanned by the crack.

We have checked numerically the existence of these localized states by diagonalizing the tight binding hamiltonian in finite lattices of different sizes. The dependence of some of the states close to the chemical potential (zero energy) on the cluster size is shown in Fig.[2]. The delocalized states show a dependence $\epsilon_{\text{del}} \propto L^{-1}$, consistent with the properties of the Dirac equation from which they can be derived. The states closest to $\epsilon = 0$, show a dependence $\epsilon_{\text{loc}} \propto L^{-2}$, which suggest a power law localization, in agreement with the previous analysis.

These states are half filled in a neutral graphene plane. In the absence of electron interactions, this leads to a large degeneracy in the ground state. A finite local repulsion will tend to induce a ferromagnetic alignment of the electrons occupying these states, as in similar cases with degenerate bands[26].

To verify this behavior and to compare with previous results we have performed an unrestricted Hartree Fock calculation of the graphene cluster with different types of defects including large vacancies as the one shown in Fig.[1]. Similar calculations done in graphene ribbons have shown non-bonding molecular orbitals localized mainly along the zigzag edges (edge states)[27, 28]. These edges have partly flat bands which give rise to a sharp peak in the density of states at the Fermi energy. A finite on-site Coulomb interaction leads to an instability of these flat bands and to the existence of spin-polarized states. We have verified that the similar behavior can

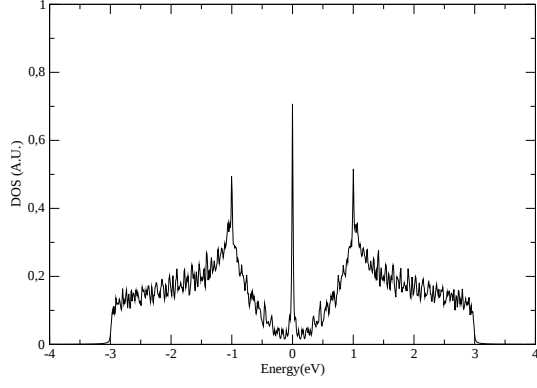


FIG. 3: Density of states of a 26×26 cluster with a large defect with zig-zag boundary as the one shown in Fig.[1] The on-site interaction term is $U = 0$.

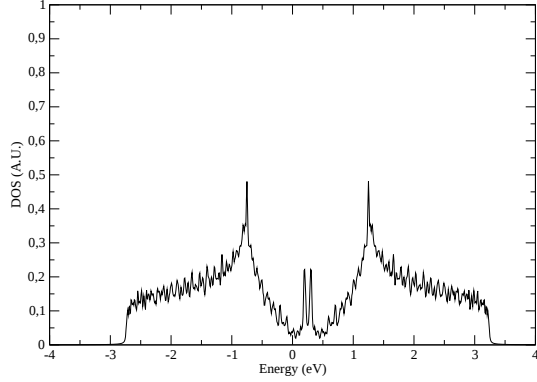


FIG. 4: Same as Fig.[3] with an on-site interaction $U = 0.5t$.

also be obtained near the boundary of a large defect as the one shown in Fig.[1]. We have performed calculations in a honeycomb lattice of various sizes with a maximum of 26×26 unit cells, i. e. a cluster of 52×52 sites. In the absence of defects the density of states is zero at the Fermi level. Figure [3] shows the charge density distribution of a lattice with an extended vacancy shaped as shown in Fig.[1], without on-site interaction. The Fermi level is located at zero. A peak in the Fermi level is formed due to the presence of the defect. The total magnetization of the cluster is zero. When the on-site interaction is switched on, a spin polarization arises of a magnitude proportional to the size of the defect. Fig.[4] shows the density profile of the polarized cluster obtained with $U = 0.5t$.

Next we will analyze the influence of these magnetic moments on the conduction band. The hopping between the states involved in the formation of these moments and the delocalized states in the conduction band vanishes by definition, if the localized states lie at zero energy. Hence, a Kondo-like coupling mediated by the hopping will not be induced. The localized electrons act as a reservoir of localized moments, which interact with the valence elec-

trons via the on site Hubbard repulsion, U . The wavefunction of the localized electrons overlaps on many sites with the valence electrons. On these sites, the valence electrons will tend to be polarized with their spins parallel to the spins of the localized electrons. The change in the energy at a given site for the valence electrons near the defect is of order U , distributed over N sites. Then, the valence electrons will induce long range RKKY interactions between the localized moments, which can be estimated by adding the contributions from all sites. We find:

$$J_{RKKY}(\tilde{\mathbf{r}}) \sim U^2 N^2 \int d^2 \mathbf{k} e^{i\tilde{\mathbf{k}}\tilde{\mathbf{r}}} \chi(\tilde{\mathbf{k}}) \sim U^2 N^2 \frac{a^4}{v_F |\tilde{\mathbf{r}}|^3} \quad (3)$$

Where a is the lattice constant, and the static susceptibility is given by: $\chi(\tilde{\mathbf{k}}) \propto |\tilde{\mathbf{k}}|^{-1}$, and a is the lattice constant.

Due to the absence of a finite Fermi surface, the RKKY interaction in eq.(3) does not have oscillations. Hence, there are no competing ferro- and antiferromagnetic couplings, and the magnetic moments will tend to be ferromagnetically aligned. The total polarization per unit area at low temperatures is proportional to Nc , where c is the concentration of defects, and N is proportional to the average size.

We can make an estimate of the Curie temperature from the coupling between the local magnetic moments given in eq.(3). The entropy cost of aligning ferromagnetically moments is $S \sim T$ per moment. The average distance between moments is $|\tilde{\mathbf{r}}| \sim c^{-1/2}$. Hence, the free energy per moment in the ferromagnetic phase can be written as:

$$\mathcal{F}(m) = \left(-c_1 \frac{U^2 N^2 a^4 c^{3/2}}{v_F} + c_2 T \right) m^2 + \dots \quad (4)$$

where c_1 and c_2 are numerical constants of order unity. The value of the free energy will be negative (and below the value in the paramagnetic phase) at a Curie temperature given by:

$$T_c \sim \frac{U^2 N^2 a^4 c^{3/2}}{v_F} \approx \frac{U^2 N a^3}{W l^3} \quad (5)$$

where W is the conduction electron bandwidth, $W \sim v_F/a$, and l is the average distance between impurities.

The Curie temperature depends on the concentration and size of the defects. Assuming, as an example, that $N \sim 10$ and $l \sim 10^2 a$, we obtain a saturation magnetization of 10^{-3} Bohr magnetons per unit cell, and a Curie temperature $T_C \sim 10^{-4} U^2/W$. The value of U^2/W can be estimated to be $\sim 1\text{eV}$. Then, these arguments give $T_C \sim 1\text{K}$. This temperature is considerably lower than the experimentally observed ones. It is worth noting, however, that this analysis does not take into account the enhancement of the susceptibility of the conduction electrons, percolation effects due to the random distribution of impurities, and the finite extension of the localized states induced by the defects.

Conclusions. We have shown that, under very general circumstances, lattice defects, vacancies and voids in the graphene structure give rise to localized states at the Fermi energy. The number of these states scales roughly with the perimeter of the defect. Repulsive electron-electron interactions lead to the polarization of these states, and to the formation of local moments. The RKKY interaction mediated by the valence electrons decays as r^{-3} , where r is the distance between defects, and shows no oscillations, due to the vanishing of the Fermi surface in a graphene layer. The interaction is ferromagnetic, and the system cannot show the frustration effects and spin glass features observed in other disordered sys-

tems with local moments. On the other hand, the Curie temperature estimated assuming a random distribution of local moments is low, $T_C \sim 1\text{K}$, for reasonable values of the defect concentration. It may happen that percolation effects, and the finite extension of the localized states which give rise to the local moments will increase the value of T_C .

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- [1] Y. Kopelevich, P. Esquinazi, J. H. S. Torres, R. R. da Silva, and H. Kempa, in *Studies of High Temperature Superconductors*, edited by A. Narlikar (Nova Science Pub., Inc, 2003), vol. 45, p. 59.
 - [2] Y. Kopelevich, P. Esquinazi, J. H. S. Torres, and S. Moehlecke, *J. Low Temp. Phys.* **119**, 691 (2000).
 - [3] P. Esquinazi, A. Setzer, R. Höhne, C. Semmelhack, Y. Kopelevich, D. Spemann, T. Butz, B. Kohlstrunk, and M. Lösche, *Phys. Rev. B* **66**, 024429 (2002).
 - [4] H. Kempa, P. Esquinazi, and Y. Kopelevich, *Phys. Rev. B* **65**, 241101 (2002).
 - [5] S. Moehlecke, P.-C. Ho, and M. B. Maple, *Phil. Mag. Lett.* **82**, 1335 (2002).
 - [6] J. M. D. Coey, M. Venkatesan, C. B. Fitzgerald, A. P. Douvalis, and I. S. Sanders, *Nature* **420**, 156 (2002).
 - [7] Y. Kopelevich, J. H. S. Torres, R. R. da Silva, F. Mrowka, H. Kempa, and P. Esquinazi, *Phys. Rev. Lett.* **90**, 156402 (2003).
 - [8] H. Kempa, H. C. Semmelhack, P. Esquinazi, and Y. Kopelevich, *Solid State Commun.* **125**, 1 (2003).
 - [9] K. h. Han, D. Spemann, P. Esquinazi, R. Höhne, R. Riede, and T. Butz, *Adv. Mat.* **15**, 1719 (2003).
 - [10] P. Esquinazi, D. Spemann, R. Höhne, A. Setzer, K.-H. Han, and T. Butz, *Phys. Rev. Lett.* **91**, 227201 (2003).
 - [11] T. L. Makarova, in *Studies of High- T_c Superconductivity*, edited by A. Narlikar (Nova Science, 2002).
 - [12] J. C. Slonczewski and P. R. Weiss, *Phys. Rev.* **109**, 272 (1958).
 - [13] J. W. McClure, *Phys. Rev.* **112**, 715 (1958).
 - [14] J. González, F. Guinea, and M. A. H. Vozmediano, *Nucl. Phys. B* **406** [FS], 771 (1993).
 - [15] J. González, F. Guinea, and M. A. H. Vozmediano, *Nucl. Phys. B* **424** [FS], 595 (1994).
 - [16] J. González, F. Guinea, and M. A. H. Vozmediano, *Phys. Rev. Lett.* **77**, 3589 (1996).
 - [17] C. de C. Chamon, C. Mudry, and X.-G. Wen, *Phys. Rev. B* **53**, R7638 (1996).
 - [18] H. E. Castillo, C. de C. Chamon, E. Fradkin, P. M. Goldbart, and C. Mudry, *Phys. Rev. B* **56**, 10668 (1997).
 - [19] B. Horovitz and P. L. Doussal, *Phys. Rev. B* **65**, 125323 (2002).
 - [20] J. González, F. Guinea, and M. A. H. Vozmediano, *Phys. Rev. B* **63**, 134421 (2001).
 - [21] T. Stauber, F. Guinea, and M. A. H. Vozmediano, *Phys. Rev. B* **71**, 041406 (2005).
 - [22] K. Wakabayashi and M. Sigrist, *Phys. Rev. Lett.* **84**, 3390 (2000).
 - [23] K. Wakabayashi, *Phys. Rev. B* **64**, 125428 (2001).
 - [24] A. A. Ovchinnikov and I. L. Shamovsky, *Journ. of. Mol. Struc. (Theochem)* **251**, 133 (1991).
 - [25] K. Harigaya, A. Yamashiro, Y. Shimoi, K. Wakabayashi, Y. Kobayashi, N. Kawatsu, K. Takai, H. Sato, J. Ravier, T. Enoki, and M. Endo, *J. Chem. Phys. Sol.* **65**, 123 (2004).
 - [26] D. Vollhardt, N. Blümer, K. Held, M. Kollar, J. Schlipf, M. Ulmke, and J. Wahle, in *Advances in Solid State Physics* (Wiley, 1999).
 - [27] A. Yamashiro, Y. Shimoi, K. Harigaya, and K. Wakabayashi, *Physica E* **22**, 688 (2004).
 - [28] A. Yamashiro, Y. Shimoi, K. Harigaya, and K. Wakabayashi, *Phys. Rev. B* **68**, 193410 (2003).